

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>V10PN50-M3/86A</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of V10PN50-M3/86A - DIODE SCHOTTKY 50V 10A TO277A

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.vishay.com

V10PN50-M3

HALOGEN **FREE**

Vishay General Semiconductor

High Current Density Surface Mount Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.30 \text{ V}$ at $I_F = 5 \text{ A}$

eSMP® Series TMBS®



TO-277A (SMPC)



PRIMARY CHARACTERISTICS			
I _{F(AV)}	10 A		
V_{RRM}	50 V		
I _{FSM}	180 A		
V _F at I _F = 10 A	0.40 V		
T _J max.	150 °C		
Package	TO-277A (SMPC)		
Diode variation	Single die		

FEATURES

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling, and polarity protection applications.

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10PN50	UNIT	
Device marking code		10N5		
Maximum repetitive peak reverse voltage	V _{RRM}	50	V	
Maximum average forward rectified current (fig. 1)	I _F ⁽¹⁾	10	Α Α	
	I _F ⁽²⁾	5.3		
Maximum DC reverse voltage	V _{DC}	35	V	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	180	А	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150	°C	

(1) Mounted on 30 mm x 30 mm 2 oz. pad PCB

(2) Free air, mounted on recommended copper pad area

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
	I _F = 5 A		0.40	-		
Instantaneous forward voltage	I _F = 10 A	$T_A = 25 ^{\circ}C$	V _F ⁽¹⁾	0.47	0.55	V
	I _F = 5 A	T _A = 125 °C		0.30	-	
	I _F = 10 A			0.40	0.49	
Reverse current	V _R = 50 V	T _A = 25 °C	I _R ⁽²⁾	50	1500	μΑ
	V _R = 50 V T _A = 125 °C	T _A = 125 °C		32	85	mA

Notes

- $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10PN50	UNIT	
Typical thermal registance	R _{0JA} (1) (2)	70	°C/W	
Typical thermal resistance	R _{0JM} (3)	4		

Notes

- $^{(1)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ junction-to-ambient
- $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (3) Mounted on 30 mm x 30 mm 2 oz. pad PCB; thermal resistance R_{0JM} junction-to-mount measured at cathode side

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V10PN50-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
V10PN50-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

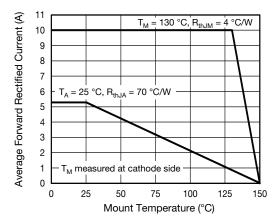


Fig. 1 - Maximum Forward Current Derating Curve (D = Duty Cycle = 0.5)

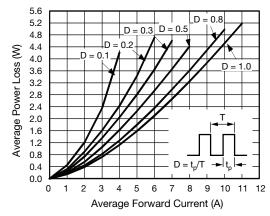


Fig. 2 - Forward Power Loss Characteristics

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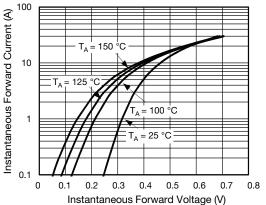


Fig. 3 - Typical Instantaneous Forward Characteristics

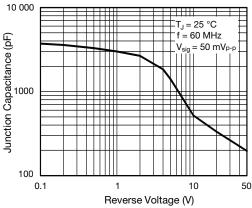


Fig. 5 - Typical Junction Capacitance

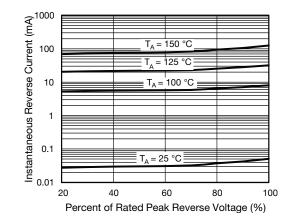


Fig. 4 - Typical Reverse Leakage Characteristics

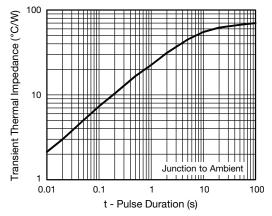


Fig. 6 - Typical Transient Thermal Impedance

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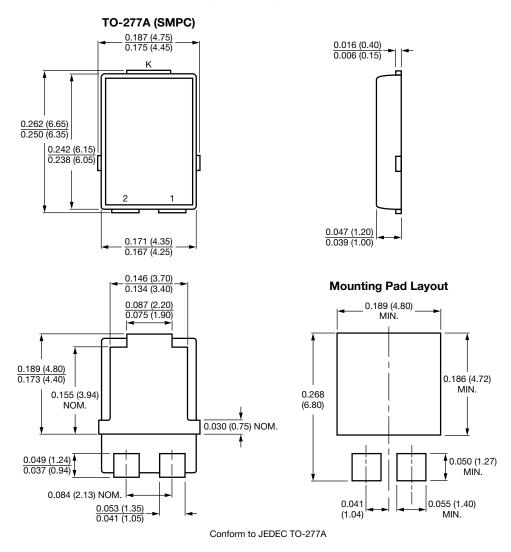
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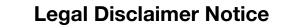
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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